Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Glass

**Overall Length:** 

0.185 inches

# **Terminal Length:**

1.000 inches

# **Overall Diameter:**

0.140 inches

#### **Function For Which Designed:**

Transient suppressor

#### Mounting Method:

Terminal

#### Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

123.5 breakdown voltage, dc

## Voltage Tolerance In Percent:

-5.0/+5.0

## **Current Rating Per Characteristic:**

10.00 milliamperes source cutoff current horsepower metric

## Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector major

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

## **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

2 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/516 government specification

#### Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

Fiig:

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